

IRMD22141SS Demo Board

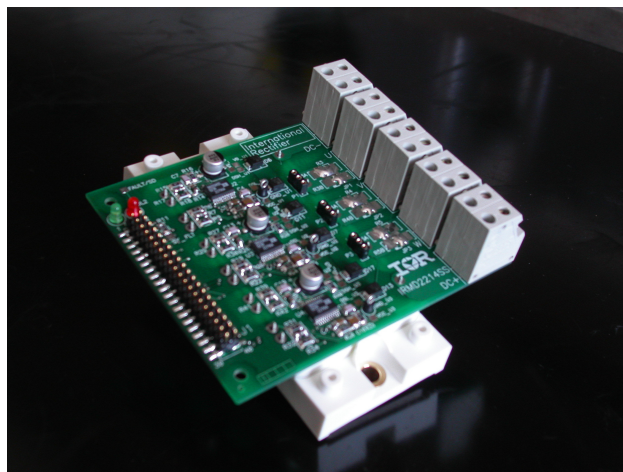
For 3-phase / 380V motor drives

IRMD22141SS Demo Board

- Up to 1200V DC-bus capability
- Up to 50A maximum phase current
- Optional on-board phase shunt resistors
- 3 x IR22141SS devices connected in 3-phase configuration
- On-board bootstrap supply for high-side gate drive
- Full protection of phase-to-phase, DC-bus and ground short circuit by monitoring IGBT de-saturation
- Fault feedback to ground level
- Internal minimum dead time
- Anti-shoot-through management
- Undervoltage lockout
- 3.3V digital input/output CMOS compatible

Power Module

- Standard ECONO2-6PACK IGBT module compatible
- IGBT short circuit rated up to 1200V/50A.
- Easy to mount heat-sink



IR22141SS Demo Board
(Shown with optional IGBT Power Module)

INTRODUCTION

The IRMD22141SS demo board is an evaluation board for IR22141SS gate driver. With three connected IR22141SS (see the device datasheet), IRMD22141SS is designed to drive 3-phase power modules with pin-out compatible to ECONO2-6PACK. The board can drive AC or Brushless motors using power modules with up to 50A output current. The board is a flexible solution for different applications and can be customized providing place for external components. The control signals are 3.3V CMOS compatible; three-phase shunt resistor (with sensing pins) can be placed for current loop control; power module short circuits are managed synchronizing the IGBT turn off in a local network. Board layout reduces the noise coupling between high and low voltage signals and EM emissions.

Application Block Diagram

(Refer to connections section to know the interface pins) This diagram shows the main blocks and connections of the demo board and the external components necessary in a typical motor drive application.

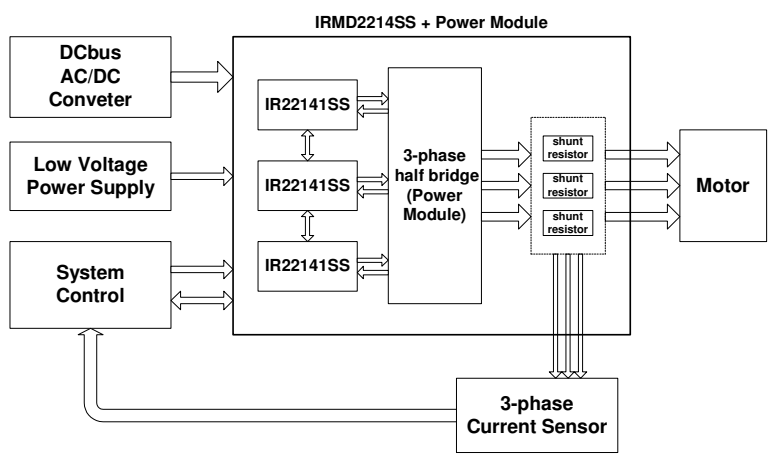


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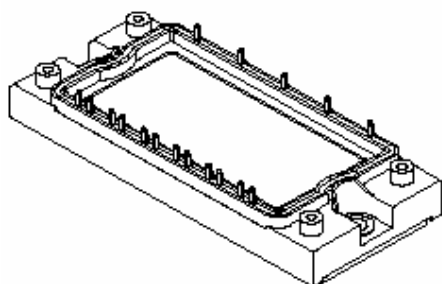
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Parameters	Values	Description, condition
Input Power		
DC+	0 to 1200V	DCBus voltage positive with 1200V power module
DC-	ground	DCbus voltage negative
Vcc	15V typ	Low voltage power supply. Follow IR22141 datasheet for supply setting
Vss	ground	Low voltage ground
Icc	100 mA	quiescent Vcc current
Output Power		
Ilmax	50A @25C	max phase dc output current
Control Inputs/Outputs		
40 pin connector J1 I/Os	3.3V to 15V compatible	see "Board Connectors" section on page 4

The IR22141SS

The IR22141SS is a half bridge gate driver suited for power switching applications. The high side driver can float up to 1200V. The IR22141SS have a high gate driving capability (2A source and 3A sink) with a low quiescent current. The device is designed to manage all the half-bridge faults by turning off smoothly the desaturated transistor through the dedicated soft shut down pin preventing over-voltages and reducing EM emissions. In a multi-phase system the drivers communicate using a dedicated local network (SY_FLT and FAULT/SD signals) to properly manage phase-to-phase short circuits. The system controller may force shutdown or read device fault state through the 3.3 V compatible CMOS I/O pin (FAULT/SD). To improve the signal immunity from DC-bus noise, the control and power ground use dedicated pins enabling low-side emitter current sensing as well. Undervoltage conditions in floating and low voltage circuits are managed independently.

For further technical information see the IR2214/IR22141 datasheet at <http://www.irf.com>.



ECONO2 6PACK

The power module

IRMD22141SS demo board is ECONO2 compatible with SixPack™ standard pin out.

Important Notice

IRMD22141SS demo board is supplied with a Bill Of Material suitable for a 1200V/50A@100C power module. The BOM presented on page 15 provides a suggestion for the above

mentioned power module.

It is strongly recommended to customize the demo board to fit the application requirements for the power module that has been chosen.

Suggestions on passive sizing are also present in "Design Tips: Using monolithic high voltage gate drivers".

BOARD CONNECTORS

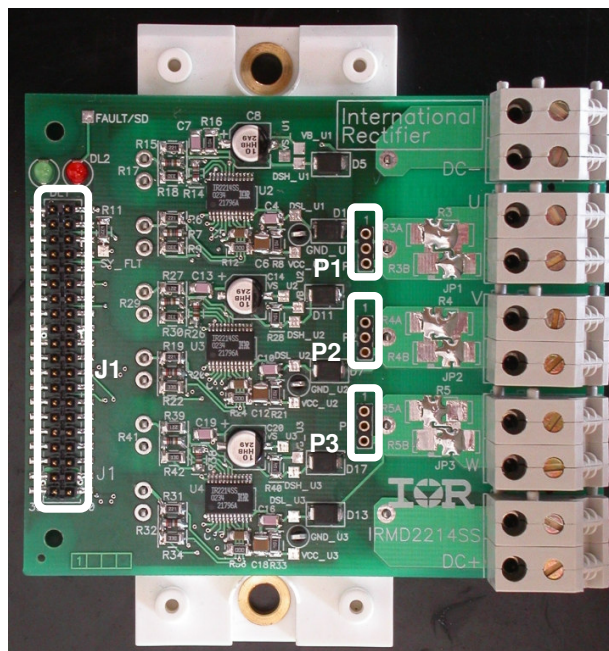


Figure 1: TOP image of board

Connection with the system controller

On board there is a 40 pins connector for the control signals. The driver board uses only 17 pins. The remaining pins are for the sensing board (IRCS2277S) that can be connected on top of IRMD22141SS board.

CONNECTOR J1		
HIN1	1	1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 29 30 31 32 33 34 35 36 37 38 39 40
LIN1	2	
HIN2	12	
LIN2	13	
HIN3	24	
LIN3	25	
FLT_CLR	3	
FAULT/SD	5/6	
VCC	37 - 40	
VSS	17 - 20	

Table 1: 40-pin connector J1

Input logical signals HIN1, LIN1, HIN2, LIN2, HIN3, LIN3 and FLT_CLR:

These logic inputs are 3.3 V compatible CMOS I/O port. The logic signals are active high with internal pull-down resistor of 10 kOhm. When both HIN and LIN of the same phase are active at the same time an internal anti-shot trough circuit turns off the output drivers. HIN turns on the high side IGBT while LIN the low side.

FLT_CLR is active high and it is used to reset the fault state of all devices (see also the Fault management section and the IR22141SS datasheet).

FAULT/SD logic signal

This is an input/output logic signal, 3.3 V compatible CMOS I/O port. The logic signal is active low, tied to connector VCC with a 10 kΩ pull-up resistor. As an input, the signal shuts down (SD) all the drivers; as an output, it reports the power module fault (IGBT desaturation detection) or the VCC undervoltage (see also IR22141SS datasheet for more information).

On board a red LED (DL2) indicates when the signal is active; Figure 2a shows the connection.

VCC supply pin

This is the supply pin for all the devices. On board a green LED (DL1) indicates the supply power on; Figure 2b shows the connection.

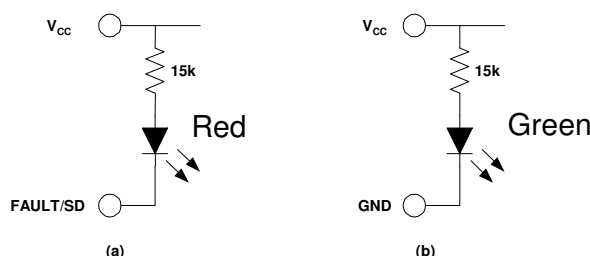


Figure 2: LED connection

VSS ground pin (GND)

The board ground is connected to the power module DC- pin. The VSS pin of the connector and the devices ground pin are star-connected to the DC- pin. DC- star connection has been chosen to reduce the noise coupled from the floating signals.

Connecting the current sensors

P1, P2 and P3 are connected with the optional shunt resistors placed on the phase output nodes.

CONNECTOR P1		
SHU+ (motor side)	1	1 2 3
SHU- (power module side)	2	
U	3	
CONNECTOR P2		
SHV+ (motor side)	1	1 2 3
SHV- (power module side)	2	
V	3	
CONNECTOR P3		
SHW+ (motor side)	1	1 2 3
SHW- (power module side)	2	
W	3	

Table 2: P1, P2 and P3 connectors for kelvin contacts to shunt signals

The SHU, SHV and SHW are sense pins connected as close as possible to the shunt resistors terminals to reduce the parasitic effects of the traces.

High power signal connector

There are two connectors dedicated to each power signal (DC+, U, V, W and DC-). Each single connector has 30 Ampere of maximal nominal dc current. DCbus traces are both on top and on one of the internal layers of the PC board in order to reduce power dissipation. Connectors, DC-bus, phase and ground wires can be soldered directly on board using the corresponding pads located under the power connectors (to be removed).

Connecting the power module

The board is fully compatible with the ECONO2-6PACK power module. The following table shows the module pin-out.

CONNECTION POINTS BETWEEN BOARD AND MODULE	
1	VGHU - phase U - high side IGBT gate
2	VEHU - phase U - high side IGBT emitter
3	VGLU - phase U - low side IGBT gate
4	VELU - phase U - low side IGBT emitter
5	VGHV - phase V - high side IGBT gate
6	VEHV - phase V - high side IGBT emitter
7	VGLV - phase V - low side IGBT gate
8	VELV - phase V - low side IGBT emitter
9	VGHW - phase W - high side IGBT gate
10	VEHW - phase W - high side IGBT emitter
11	VGLW - phase W - low side IGBT gate
12	VELW - phase W - low side IGBT emitter
13	DC+
14	Phase W
15	Phase V
16	Phase U
17	DC- (GND)

Table 3: High power module connection

Test Points

Test points on board provide signals that are not available at the connectors. See the following table:

ONE FOR EACH DEVICE (U1 -> U, U2 -> V, U3 -> W)	
V_B	High side floating supply voltage
V_S	High side floating supply offset voltage
DSH	High side desat input voltage
DSL	Low side desat input voltage
VCC	Low side and logic fixed supply voltage
GND	Device VSS
COMMON FOR ALL DEVICES	
FAULT/SD	Fault and Shut Down (or-wired)
SY_FLT	Synchronized Fault (or-wired)

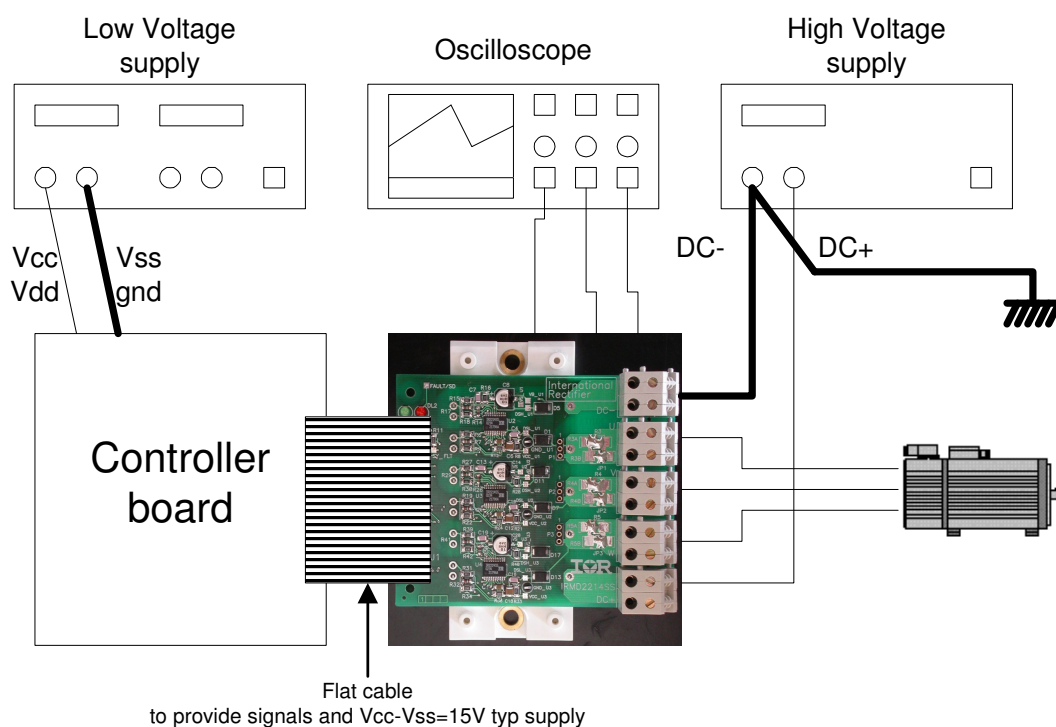
Table 4: Test points

Note: the FAULT/SD signal is present on pin 5 and 6 of the 40-pin connector, too.

TEST BENCH CONNECTION

IRMD22141SS does NOT provide opto isolation.

The following picture shows the recommended connections for board evaluation. Bold lines are equipotential (DC=Vss=gnd).



OPERATING DESCRIPTION

Power on sequence

Before beginning the normal operating mode, it is strongly recommended to follow the power ON sequence. The purpose of this procedure is to set the internal device logic. This is achieved by charging all bootstrap capacitors for the first time with the FLT_CLR signal active. See Figure 4 for the correct procedure.

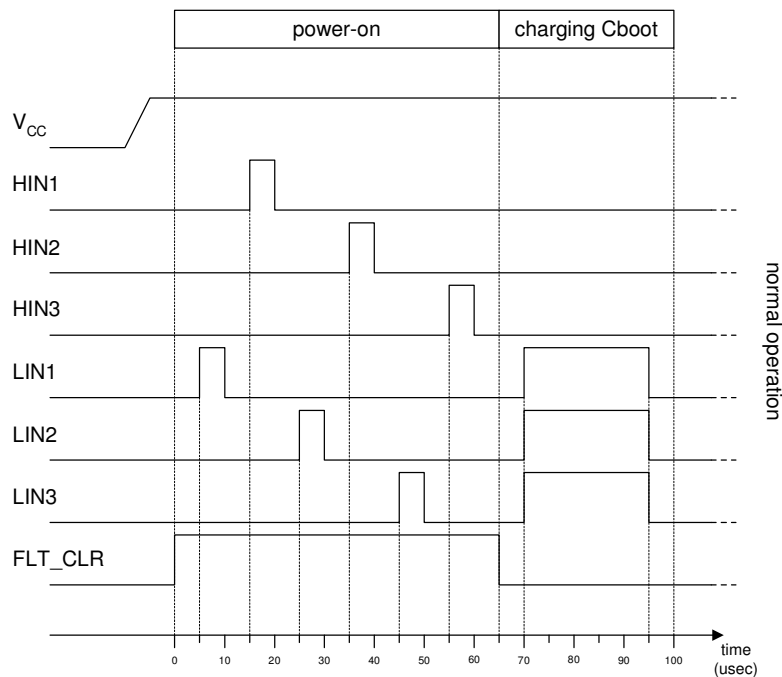


Figure 4: Power on sequence

Normal operating mode

In the normal operating mode when HIN or LIN is active the high or low side IGBT turns on respectively. Turn on and turn off propagation delays and the propagation delay matching are specified in the IR22141SS datasheet. Devices introduce also a minimum dead-time (typical 330 ns).

Fault management

The IR22141SS is able to detect the excessive current increase by monitoring the IGBT desaturation. The three-phase connection of the IR22141SS allows managing all power module faults using the FAULT/SD and SYNC_FLT signals in a local network.

Figure 5 shows how the devices are interconnected to each other and with the FAULT/SD pin on the connector. The fault management procedure starts when one of the drivers senses the IGBT desaturation (see Figure 5 where, as an example, only one low side IGBT is shown).

Figure 6 shows an example where the low side IGBT of U1 and U3 and the high side of U2 are on. The procedure is totally managed by an integrated FAULT LOGIC block without the controller assistance.

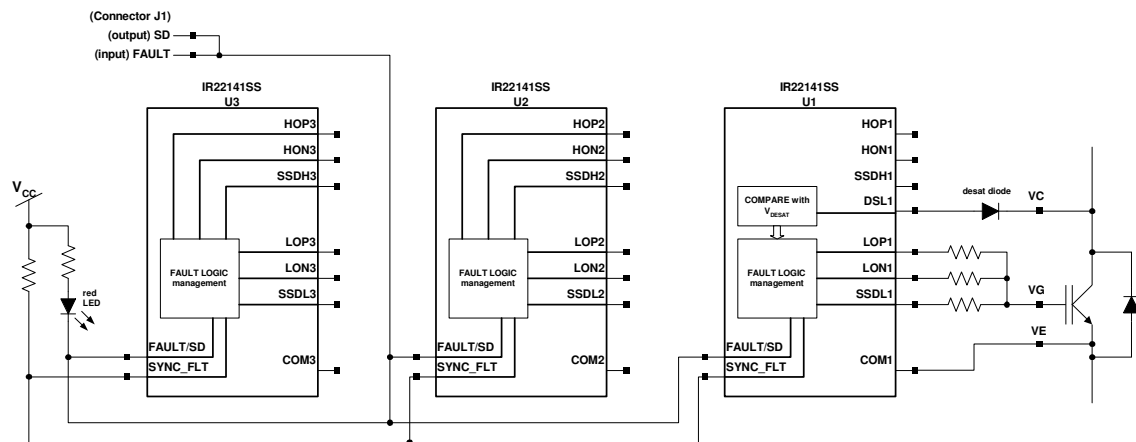


Figure 5: Three phase connection

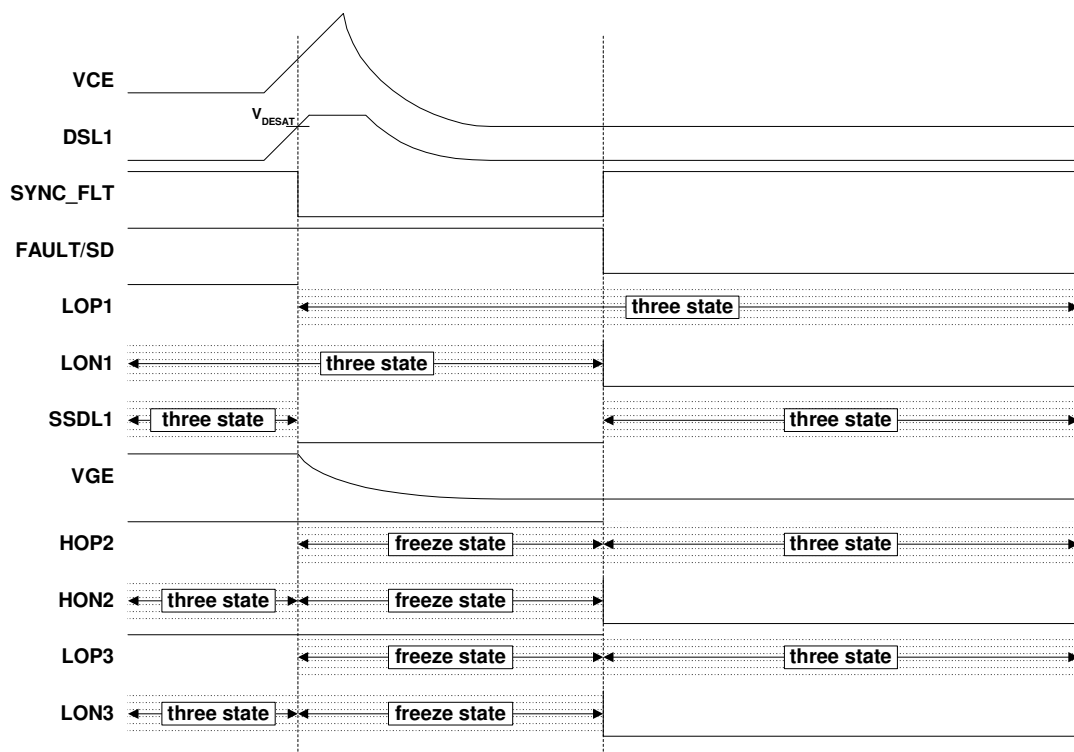


Figure 6: Example of a desaturation detection event

Multilevel board solution

With the optional shunt resistor the IRMD22141SS driver board can be connected with the IRCS2277S current sensing board through J1 and P1, P2, and P3 connectors. More information available with IRCS2277S board datasheet.

BOARD SOLUTIONS

Sizing of the components mentioned in this section is indicated in the Bill of material on page 15.

Bootstrap circuit

The high side floating supply (V_{BS}) is provided by a bootstrap capacitor. Figure 7 shows the circuit on board.

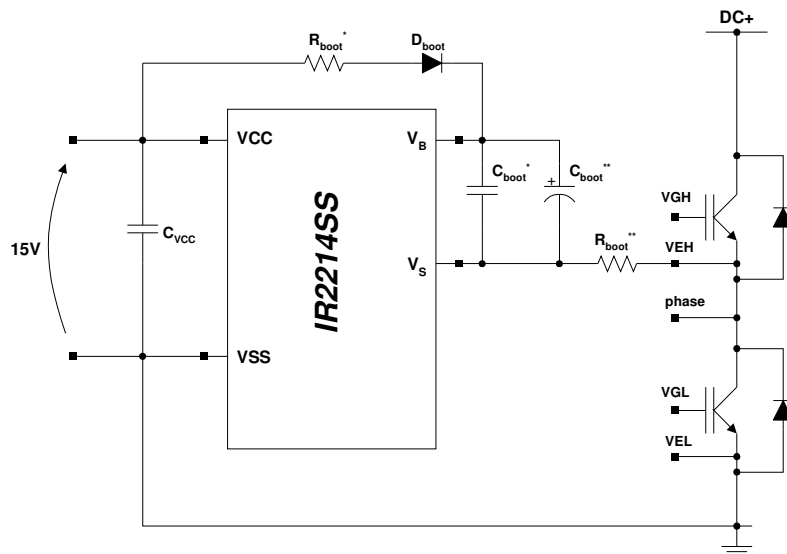


Figure 7: Bootstrap circuit

The following table shows the names of these components on board.

	U	V	W
C_{VCC}	C5	C11	C17
C_{boot}^*	C9	C15	C21
C_{boot}^{**}	C8	C14	C20
R_{boot}^*	R13	R25	R37
R_{boot}^{**}	R14	R26	R38

Gate resistances

The following table shows the names of gate resistances on board.

	U	V	W
high side gate to HOP	R18	R30	R42
high side gate to HON	R17	R29	R41
high side gate to SSDH	R15	R27	R39
low side gate to LOP	R9	R22	R34
low side gate to LON	R7	R20	R32
low side gate to SSDL	R6	R19	R31

OTHER EXTRA COMPONENTS

These components are provided to make IRMD22141SS board as customizable as possible. In many cases the extra components are not required.

Desat circuit

The IR22141S is able to detect the IGBT desaturation. To reject the noise on the desat pins the IR22141SS have an internal filter of 1 μ sec. If this is not enough an RC filter has been placed on board (see figure 8, R_{DSH} , C_{DSH} and R_{DSL} , C_{DSL}).

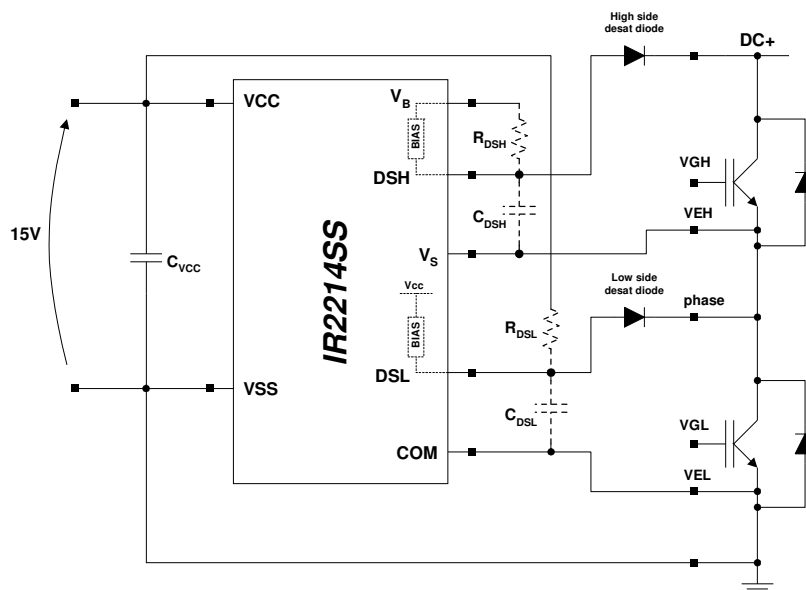


Figure 8: Desat external filter

The external resistor is in parallel with the internal bias circuit of the desat diode. If added, the external resistor may cause a higher diode bias current that must be taken into account in bootstrap capacitor sizing.

External RC filter delays desaturation detection, that causes a delay in turning the IGBT off. Consider this delay when sizing the soft-shut-down resistors.

The following table shows the names of these components on board.

	U	V	W
C_{DSH}	C7	C13	C19
R_{DSH}	R16	R28	R40
C_{DSL}	C4	C10	C16
R_{DSL}	R8	R21	R33

Clamping Diode for V_S below ground

This solution preserves the device when the V_S pin goes below ground out of the device absolute maximum ratings. The V_S voltage is clamped to the maximum value allowed by a zener diode.

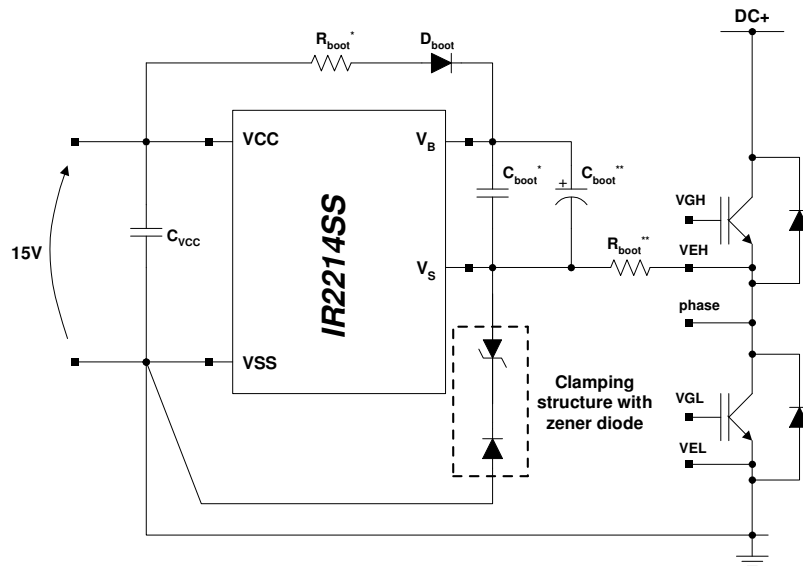


Figure 9: -Vs clamp

The following table shows the names of these components on board.

	U	V	W
DIODE	D4	D10	D16
ZENER	Z2	Z5	Z8

RC filter on com pin

An RC filter (R_{COM} , C_{COM}) is provided to preserve the IC device from low side IGBT emitter undervoltage spikes.

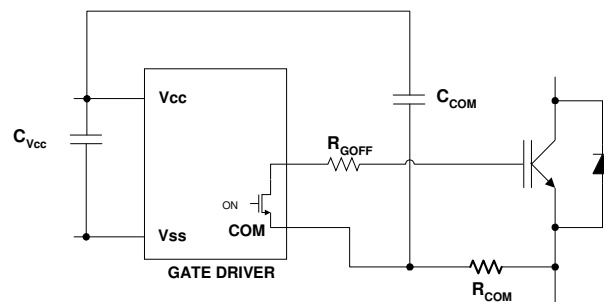


Figure 10: COM below ground protection

The following table shows the names of these components on board.

	U	V	W
C_{COM}	C6	C12	C18
R_{COM}	R10	R23	R35

Fast diode between gate and supply pin

On all low and high side drivers a fast diode is provided to clamp the gate coming over the V_{CC} or V_B supply pins and to recover the current coming from the collector node through the gate-collector capacitance.

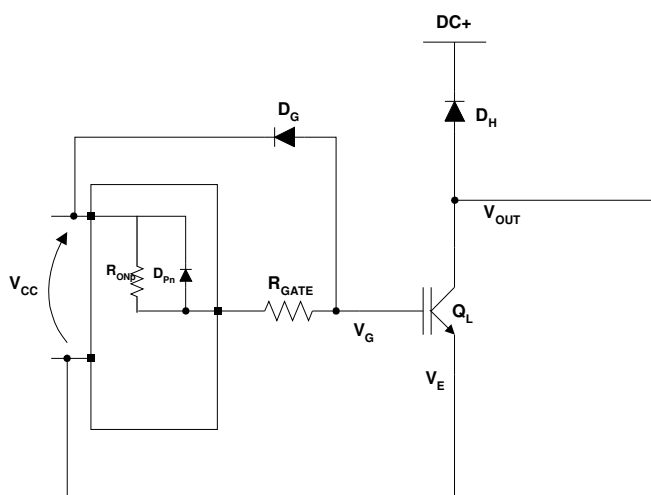


Figure 11: Collector-Gate current protection

The following table shows the names of these components on board.

	U	V	W
(high side) D_G	D6	D12	D18
(low side) D_G	D2	D8	D14

Zener diode to preserve the IGBT gate

To avoid a V_{GE} increasing over the absolute maximum rating a zener diode is connected between gate and emitter pins on all the IGBTs.

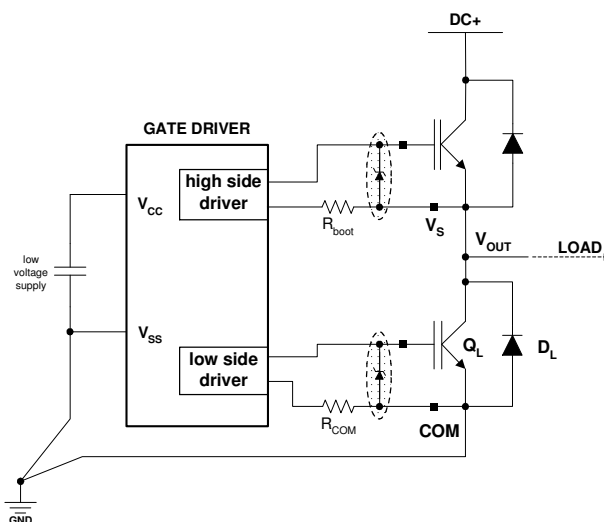


Figure 12: Zener clamp for IGBT gate

The following table shows the names of these components on board.

	U	V	W
(high side) ZENER	Z3	Z6	Z9
(low side) ZENER	Z1	Z4	Z7

Optional output shunt resistor

Two type of output shunt resistor, for current sensor, are possible see the following table:

	U	V	W
TO220 or	R3	R4	R5
OARS-1	R3A // R3B	R4A // R4B	R5A // R5B

The OARS-1 type (A and B) are connected in parallel.

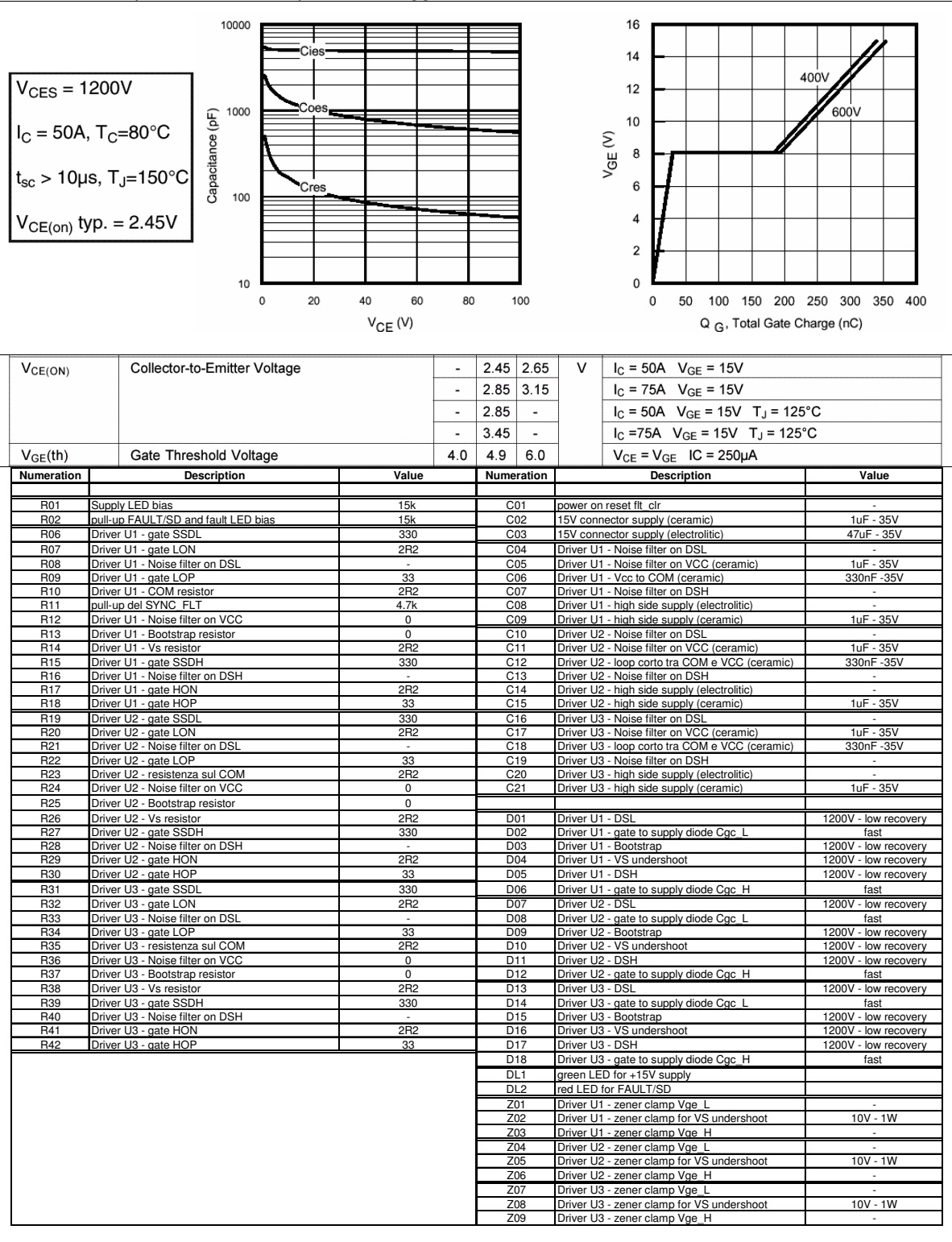
Resistor on V_{CC}

Provided to decouple V_{CC_U1} , V_{CC_U2} and V_{CC_U3} from supply line.

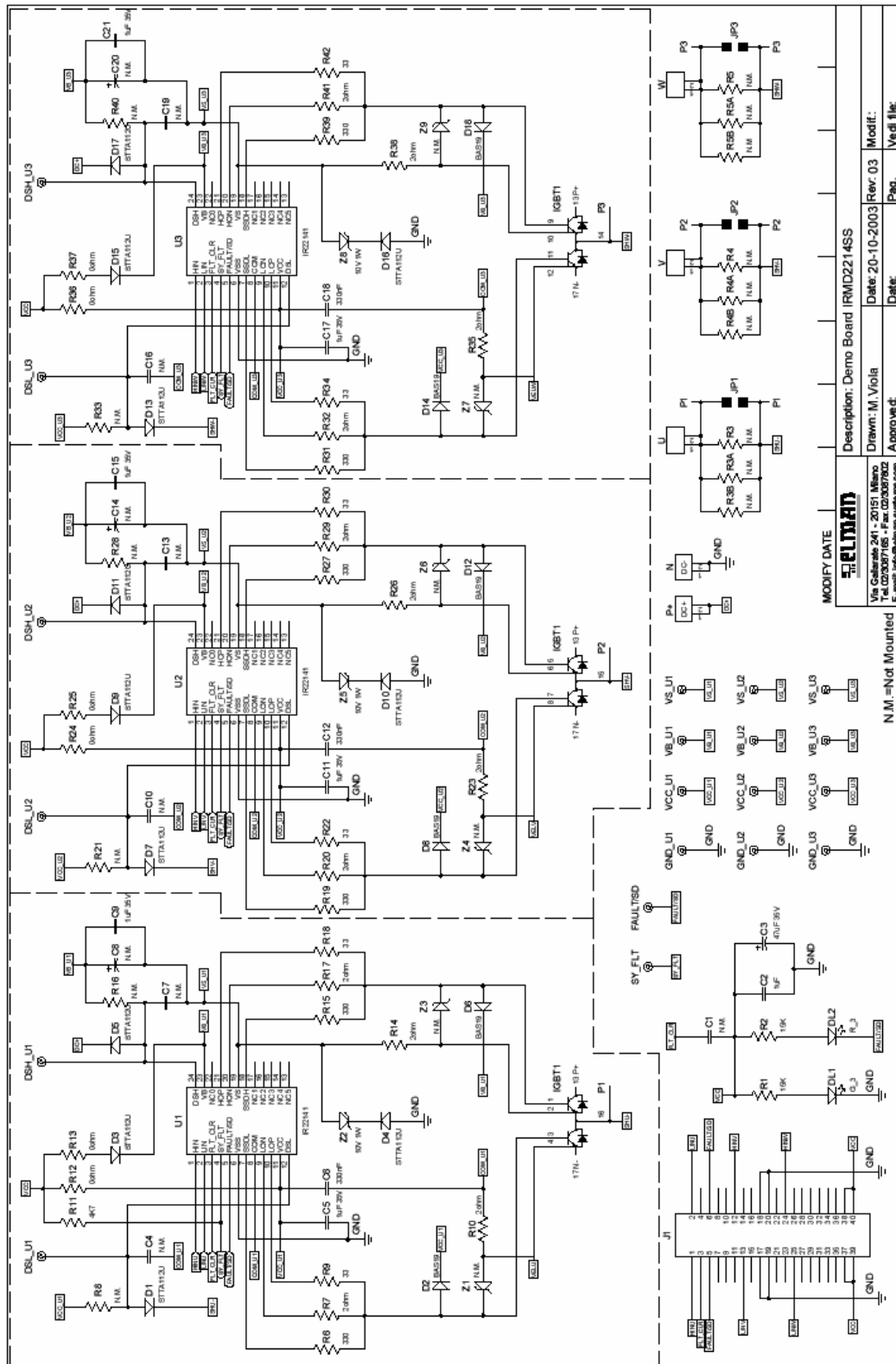
	U	V	W
Vcc decoupling	R12	R24	R36

BILL OF MATERIAL

The hereafter provided BOMs represent a suggestion based on the IGBT characteristics shown below.



SCHEMATIC



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MODIFY DATE
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Approved:
Date: 20-10-2003 Rev: 03
Pag. 1

LAYOUT

